SFH 4775S

SYNIOS® P2720

IR SYNIOS P2720 (940 nm) - 120°





Applications

CCTV SurveillanceEye Tracking

Features:

- Package: clear silicone

- Corrosion Robustness Class: 3B

- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

- IR lightsource with high efficiency

- Double stack emitter

- Low thermal resistance (Max. 9 K/W)

- Centroid wavelength 940 nm

Ordering Information

| Туре | Total radiant flux $^{1)2)}$ $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$ Φ_e | Total radiant flux $^{1)}$ typ. $I_{\rm F}$ = 1000 mA; $t_{\rm p}$ = 10 ms $\Phi_{\rm e}$ | Ordering Code |
|-----------|--|---|---------------|
| SFH 4775S | 1000 1600 mW | 1,360 mW | Q65112A7448 |



Maximum Ratings

| $T_{\wedge} =$ | 25 | $^{\circ}C$ |
|----------------|----|-------------|
|----------------|----|-------------|

| Parameter | Symbol | Values | |
|---|------------------|--------------|------------------|
| Operating temperature | T _{op} | min. max. | -40 °C 100 °C |
| Storage temperature | T_{stg} | min. max. | -40 °C 100 °C |
| Junction temperature | T _i | max. | 145 °C |
| Forward current | I _F | max. | 1500 mA |
| Forward Current pulsed $t_p \le 800 \ \mu s; \ D \le 0.005$ | F pulse | max. | 3 A |
| Reverse current 3) | I _R | max. | 200 mA |
| Power consumption | P _{tot} | max. | 5400 mW |
| ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2) | $V_{\rm ESD}$ | max. | 2 kV |

For the forward current and power consumption please see "maximum permissible forward current" diagram



Characteristics

 $I_{\scriptscriptstyle F}$ = 1000 mA; $t_{\scriptscriptstyle p}$ = 10 ms; $T_{\scriptscriptstyle A}$ = 25 °C

| Parameter | Symbol | Values | |
|--|----------------------------|--------------|------------------|
| Peak wavelength | λ_{peak} | typ. | 950 nm |
| Centroid wavelength | $\lambda_{	ext{centroid}}$ | typ. | 940 nm |
| Spectral bandwidth at 50% I _{rel,max} (FWHM) | Δλ | typ. | 37 nm |
| Half angle | φ | typ. | 60 ° |
| Dimensions of active chip area | LxW | typ. | 1 x 1 mm x mm |
| Rise time (10% / 90%) $I_F = 3 \text{ A}; R_L = 50 \Omega$ | t _r | typ. | 12 ns |
| Fall time (10% / 90%) $I_F = 3 \text{ A}; R_L = 50 \Omega$ | t _f | typ. | 15 ns |
| Forward voltage 4) | V_{F} | typ. max. | 2.9 V 3.4 V |
| Forward voltage $^{4)}$ I _F = 1.5 A; t _p = 100 µs | V_{F} | typ. max. | 3.05 V 3.6 V |
| Forward voltage ⁴⁾ I _F = 3 A; t _p = 100 µs | V_{F} | typ. max. | 3.5 V 4.2 V |
| Reverse voltage ³⁾ I _R = 20 mA | V_R | max. | 1.2 V |
| Reverse voltage (ESD device) 3) | $V_{_{ m RESD}}$ | min. | 5 V |
| Radiant intensity 5) | l _e | typ. | 420 mW/sr |
| Radiant intensity $^{5)}$ I _F = 1.5 A; t _p = 100 µs | l _e | typ. | 620 mW/sr |
| Total radiant flux ¹⁾ $I_F = 1.5 \text{ A}; t_p = 100 \mu\text{s}$ | Фе | typ. | 2000 mW |
| Temperature coefficient of voltage | TC_{v} | typ. | -2 mV / K |
| Temperature coefficient of brightness | TC, | typ. | -0.3 % / K |
| Temperature coefficient of wavelength | TC _λ | typ. | 0.3 nm / K |
| Thermal resistance junction solder point real 6) | $R_{\text{thJS real}}$ | max. | 9.0 K / W |



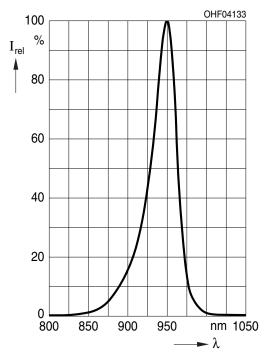
Brightness Groups

| Group | Total radiant flux $^{1)2)}$ $I_F = 1000$ mA; $t_p = 10$ ms min. Φ_e | Total radiant flux $^{1)2)}$ I _F = 1000 mA; t _p = 10 ms max. Φ_e |
|-------|---|---|
| EB2 | 1000 mW | 1120 mW |
| FA1 | 1120 mW | 1250 mW |
| FA2 | 1250 mW | 1400 mW |
| FB1 | 1400 mW | 1600 mW |

Only one group in one packing unit (variation lower 1.6:1).

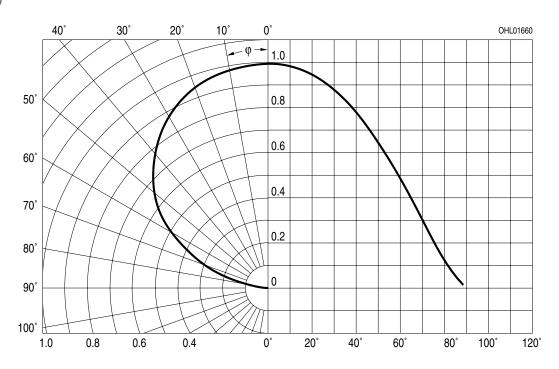
Relative Spectral Emission 7), 8)

$$I_{e,rel} = f(\lambda); I_{F} = 1000 \text{ mA}; t_{p} = 10 \text{ ms}$$



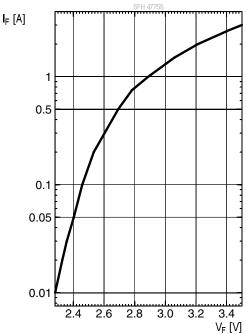
Radiation Characteristics 7), 8)

$$I_{e,rel} = f(\phi)$$



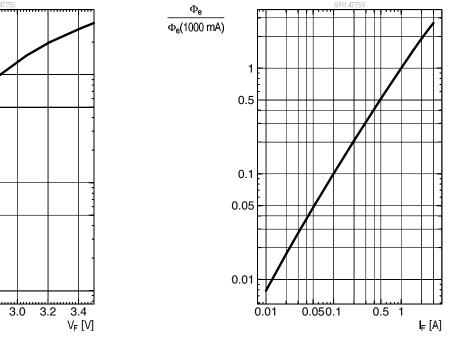
Forward current 7), 8)

 $I_F = f(V_F)$; single pulse; $t_D = 100 \mu s$



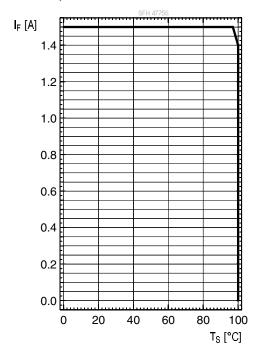
Relative Total Radiant Flux 7), 8)

 $\Phi_{\rm e}/\Phi_{\rm e}(1000{\rm mA})$ = f (I_F); single pulse; t_p = 100 $\mu {\rm s}$



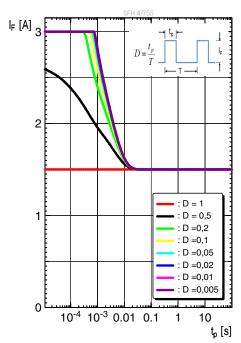
Max. Permissible Forward Current

$$I_{F,max} = f(T_S); Rth_{js} = 9K / W$$

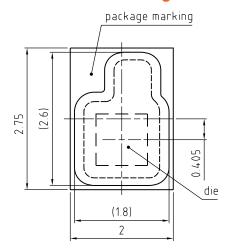


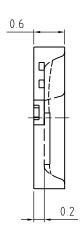
Permissible Pulse Handling Capability

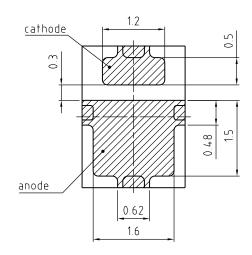
 $I_F = f(t_p)$; duty cycle D = parameter; $T_S = 85^{\circ}C$



Dimensional Drawing 9)







General tolerance ±0.1

Lead finish Au

C67062-A0183-A1-02

Further Information:

Approximate Weight: 12.0 mg

Package marking: Cathode

Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC

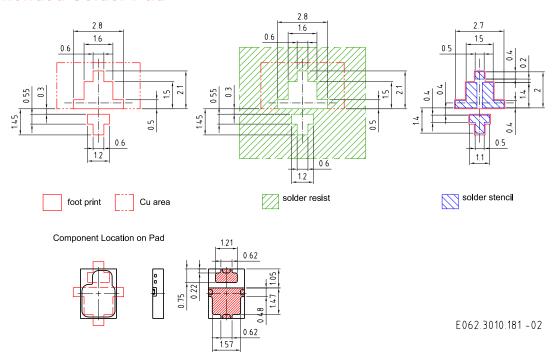
60068-2-43)

ESD advice: The device is protected by ESD device which is connected in parallel to the

Chip.

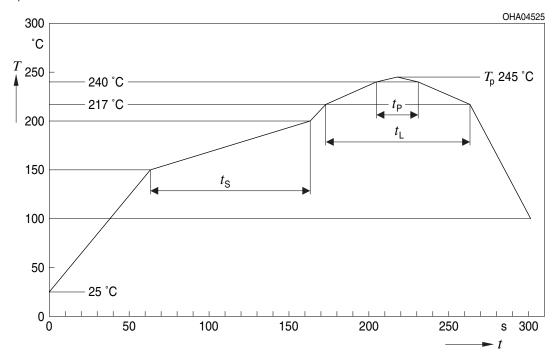


Recommended Solder Pad 9)



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



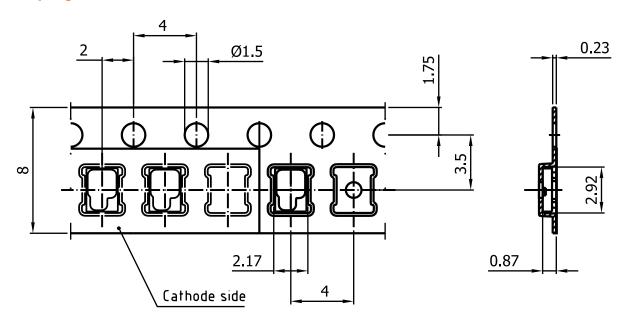
| Profile Feature | Symbol | Pb-Free (SnAgCu) Assembly | | | Unit |
|---|-----------------------------|---------------------------|----------------|---------|------|
| | | Minimum | Recommendation | Maximum | |
| Ramp-up rate to preheat*) | | | 2 | 3 | K/s |
| 25 °C to 150 °C | | | | | |
| Time t _s | $t_{\scriptscriptstyle{S}}$ | 60 | 100 | 120 | S |
| T_{Smin} to T_{Smax} | | | | | |
| Ramp-up rate to peak*) | | | 2 | 3 | K/s |
| T_{Smax} to T_{P} | | | | | |
| Liquidus temperature | T_{L} | | 217 | | °C |
| Time above liquidus temperature | $t_{\scriptscriptstyle L}$ | | 80 | 100 | S |
| Peak temperature | T_{P} | | 245 | 260 | °C |
| Time within 5 °C of the specified peak temperature T _P - 5 K | t _P | 10 | 20 | 30 | S |
| Ramp-down rate* | | | 3 | 6 | K/s |
| T _P to 100 °C | | | | | |
| Time | | | | 480 | S |
| 25 °C to T _P | | | | | |

All temperatures refer to the center of the package, measured on the top of the component



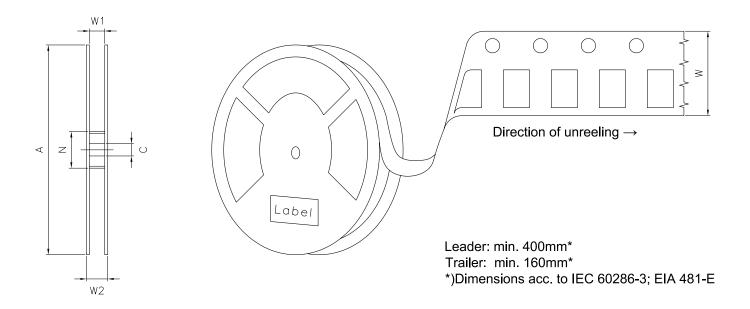
^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Taping 9)



C67062-A0116-B14-04

Tape and Reel 10)



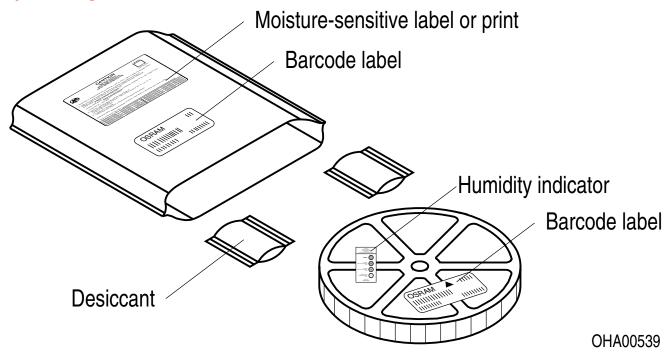
Reel Dimensions

| Α | W | N_{\min} | W_1 | $W_{2 \text{ max}}$ | Pieces per PU |
|--------|--------------------|------------|------------|---------------------|---------------|
| 180 mm | 8 + 0.3 / - 0.1 mm | 60 mm | 8.4 + 2 mm | 14.4 mm | 2000 |

Barcode-Product-Label (BPL)



Dry Packing Process and Materials 9)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

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Glossary

- Total radiant flux: Measured with integrating sphere.
- Brightness: The brightness values are measured with a tolerance of $\pm 11\%$.
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Forward Voltage: The forward voltages are measured with a tolerance of ±0.1 V.
- Radiant intensity: Measured at a solid angle of Ω = 0.01 sr
- Thermal resistance: junction soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁸⁾ **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ¹⁰⁾ **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



SFH 4775S

| Revision History | | | | |
|------------------|------------|---|--|--|
| Version | Date | Change | | |
| 1.1 | 2020-01-28 | Brightness and Wavelenght Groups | | |
| 1.2 | 2020-08-26 | Schematic Transportation Box Dimensions of Transportation Box | | |
| 1.3 | 2021-04-06 | Notes | | |
| 1.4 | 2021-09-15 | Ordering Information Maximum Ratings Characteristics Electro - Optical Characteristics (Diagrams) | | |



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